## NSN 5961-00-443-4413

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View Online at https://aerobasegroup.com/nsn/5961-00-443-4413

Inclosure Material:

Metal

**Overall Length:** 

0.320 inches

**Overall Diameter:** 

0.437 inches

Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.437 inches

**Thread Size:** 

0.190 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

65.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 200.00 milliamperes source cutoff current and 1.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

11.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### **Specification Data:**

80131-release5400 professional/industrial association specification

### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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